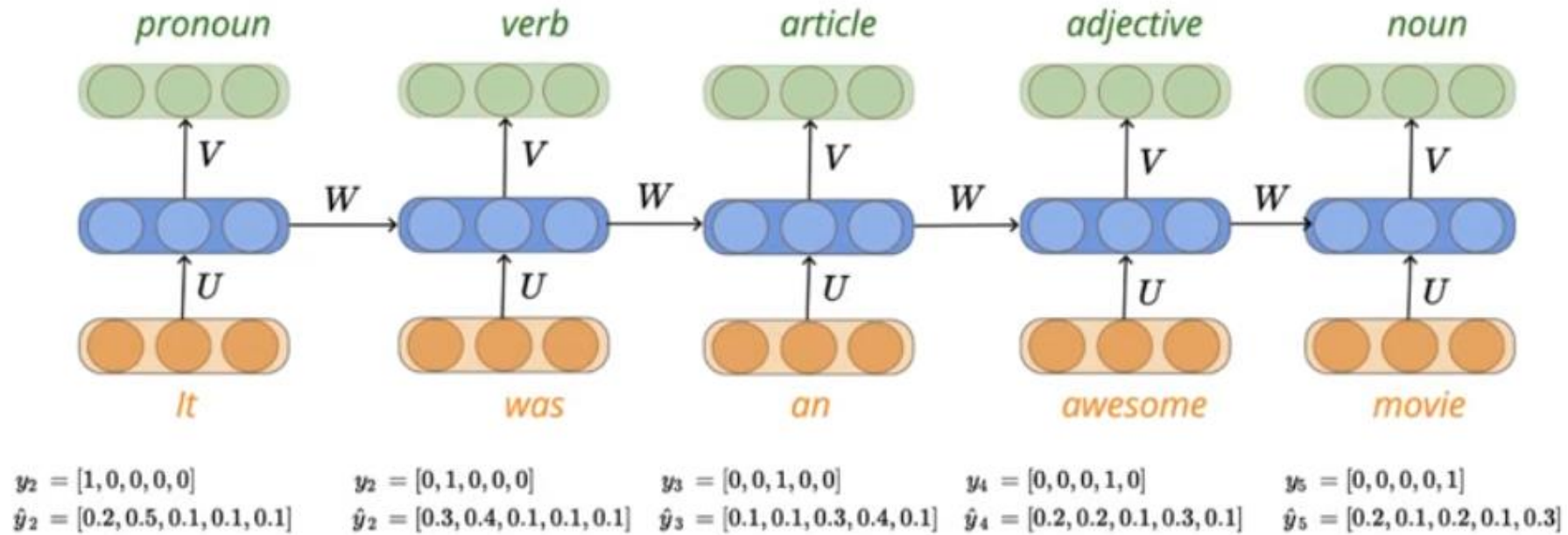


Deep Learning : Dealing with Longer Sequences – LSTMs and GRUs

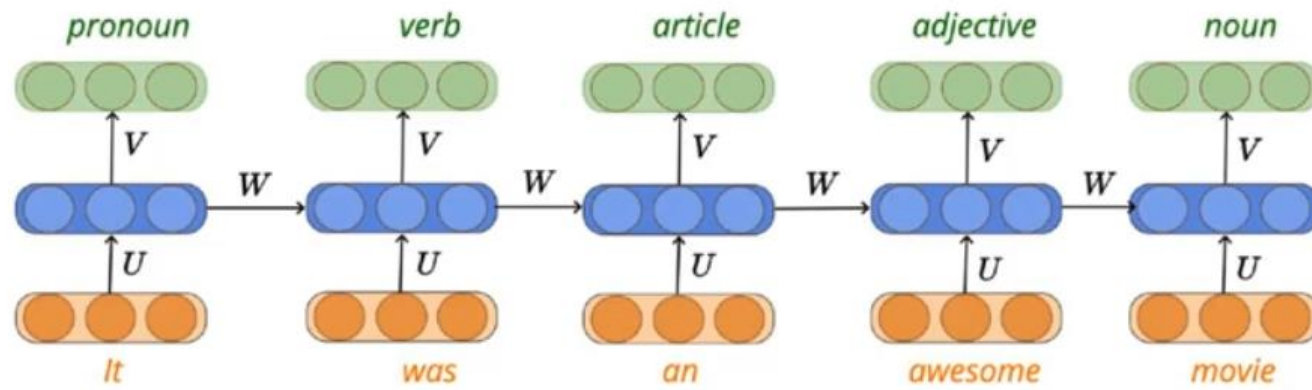


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Recurrent Neural Network (RNNs)



- ✗ At each new timestep the old information gets morphed by the current input
- ✗ One could imagine that after t steps the information stored at time step $t - k$ (for some $k < t$) gets completely morphed
- ✗ Even during backpropagation the information does not flow well

Dealing with Longer Sequences

$$a = 1 \quad b = 3 \quad c = 5 \quad d = 11$$

Compute $ac(bd + a) + ad$

① ac

$$ac = 5$$

② bd

$$bd = 33$$

③ $bd + a$

$$bd + a = 34$$

④ $ac(bd + a)$

⑤ ad

⑥ $ac(bd + a) + ad$

Strategy

- ✓ Selectively write on the board
- ✓ Selectively read the already written content
- ✓ Selectively forget (erase) some content

Whiteboard Analogy

$$a = 1 \quad b = 3 \quad c = 5 \quad d = 11$$

Compute $ac(bd + a) + ad$

① ac

$$ac = 5$$

② bd

③ $bd + a$

$$ac(bd + a) = 170$$

④ $ac(bd + a)$

$$bd + a = 34$$

⑤ ad

⑥ $ac(bd + a) + ad$

Strategy

- ✓ Selectively write on the board
- ✓ Selectively read the already written content
- ✓ Selectively forget (erase) some content

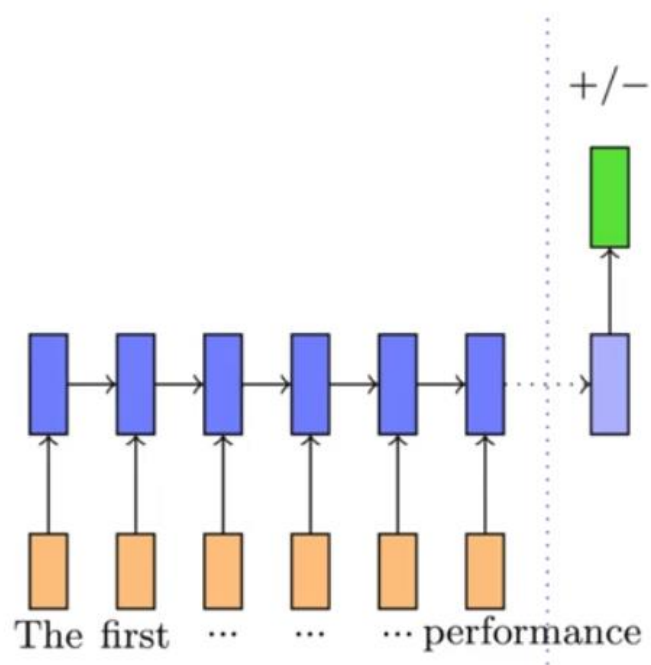
Whiteboard Analogy

Since the RNN also has a finite state size, we need to figure out a way to allow it to selectively read, write and forget

Strategy

- ✓ Selectively write to the state
- ✓ Selectively read the already written content
- ✓ Selectively forget (erase) some content

Can we use similar strategy in RNNs?

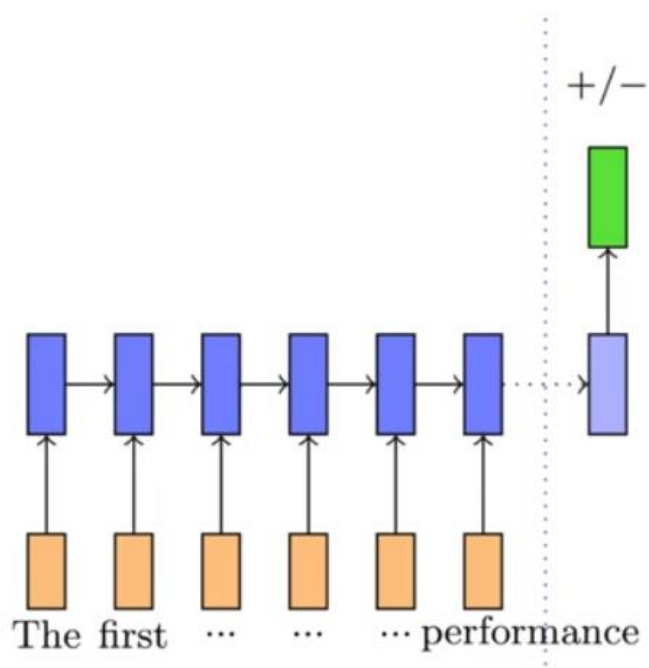


Review: The first half of the movie was dry but the second half really picked up pace. The lead actor delivered an amazing performance

Ideally, we want to

- ✓ forget the information added by stop words (a, the, etc.)
- ✓ selectively read the information added by previous sentiment bearing words (awesome, amazing, etc.)
- ✓ selectively write new information from the current word to the state

Can we use similar strategy in RNNs?

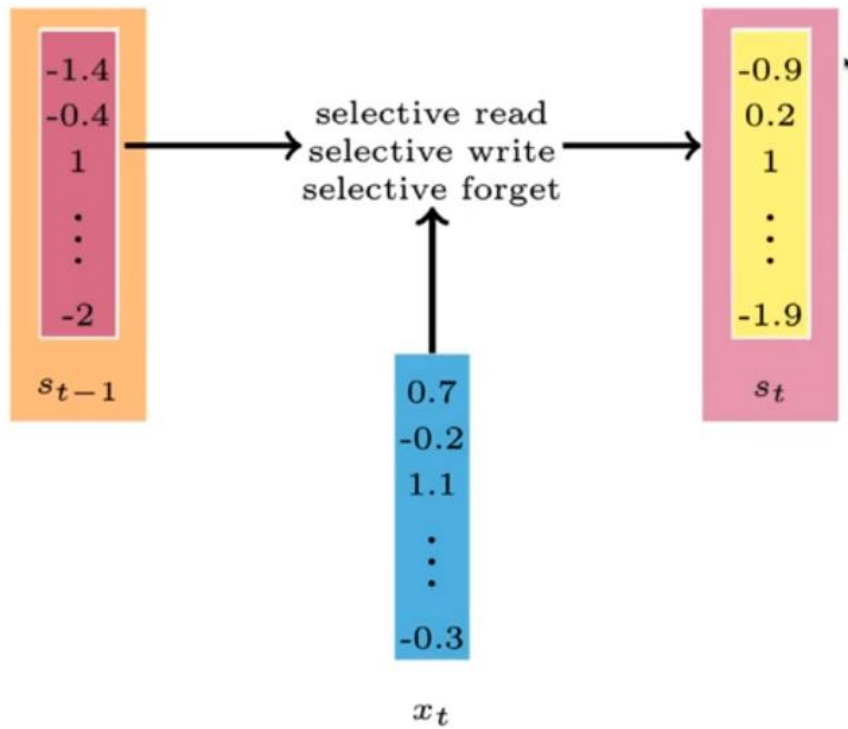


Review: The first half of the movie was dry but the second half really picked up pace. The lead actor delivered an amazing performance



Wishlist: selective write, selective read and selective forget to ensure that this finite sized state vector is used effectively

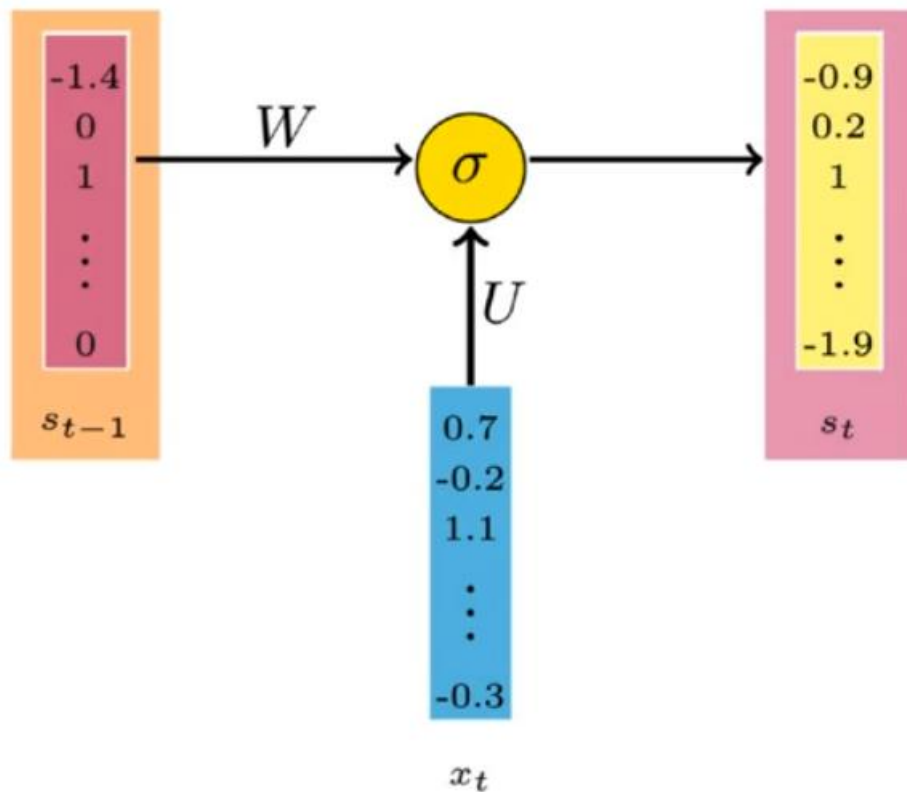
Wishlist – Dealing with longer sequences



While computing s_t from s_{t-1} we want to make sure that we use selective write, selective read and selective forget so that only important information is retained in s_t

Long Short Term Memory Cells

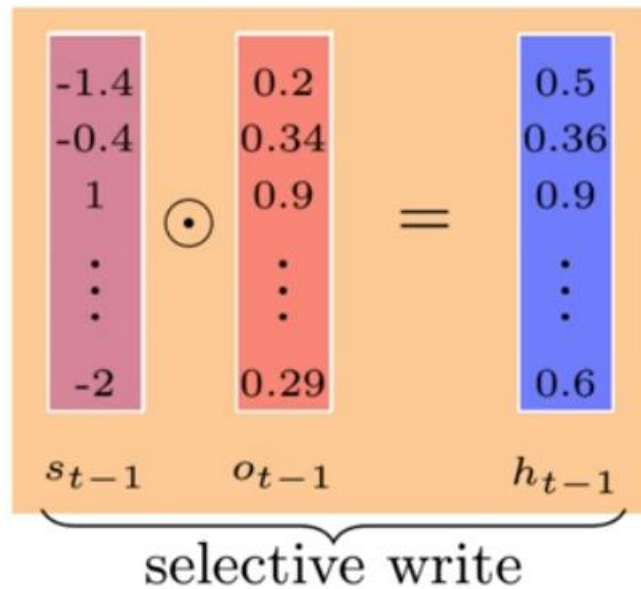
How do you implement selective read, write and forget?



$$s_t = \sigma(Ux_t + Ws_{t-1} + b)$$

- ✓ instead of passing s_{t-1} as it is to s_t we want to pass (write) only some portions of it to the next state
- ✓ A reasonable way of doing this would be to assign a value between 0 and 1 which determines what fraction of the current state to pass on to the next state

Selective Write



x_t

$\begin{bmatrix} 0.7 \\ -0.2 \\ 1.1 \\ \vdots \\ -0.3 \end{bmatrix}$

x_t

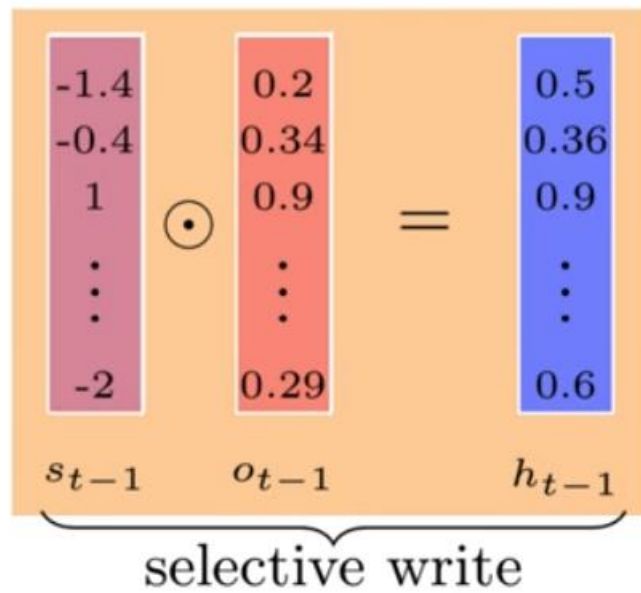
s_t

$\begin{bmatrix} -1.4 \\ -0.4 \\ 1 \\ \vdots \\ -2 \end{bmatrix}$

But how do we compute o_{t-1} ?
How does the RNN know what fraction of the state to pass on?

- ✓ learn o_{t-1} from data
- ✓ the only thing that we learn from data is parameters
- ✓ **Solution:** express o_{t-1} using parameters

Selective Write



x_t

$\begin{bmatrix} 0.7 \\ -0.2 \\ 1.1 \\ \vdots \\ -0.3 \end{bmatrix}$

s_t

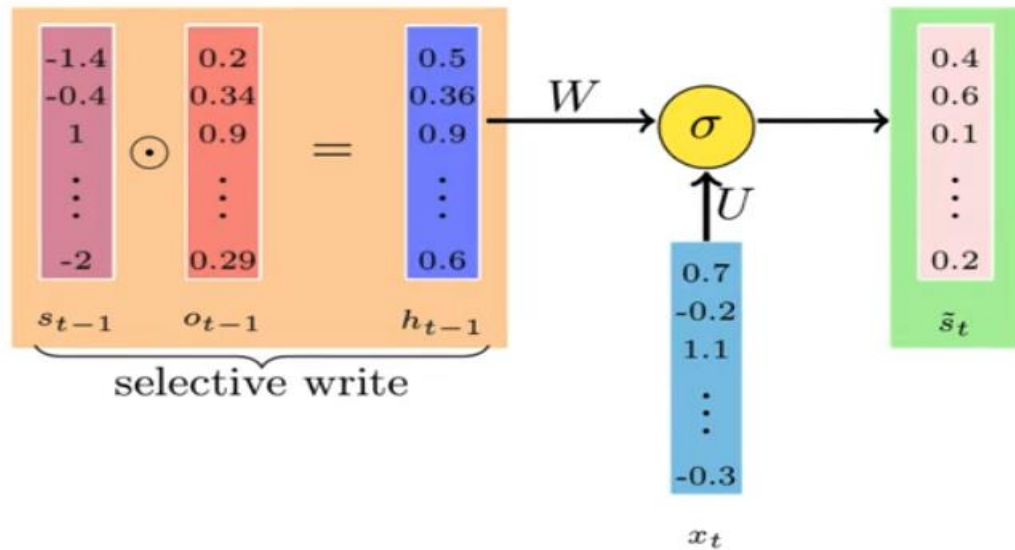
$\begin{bmatrix} -1.4 \\ -0.4 \\ 1 \\ \vdots \\ -2 \end{bmatrix}$

$$o_{t-1} = \sigma(U_o x_{t-1} + W_o h_{t-2} + b_o)$$

$$h_{t-1} = s_{t-1} \odot o_{t-1}$$

o_t is called the **output** gate

Selective Write

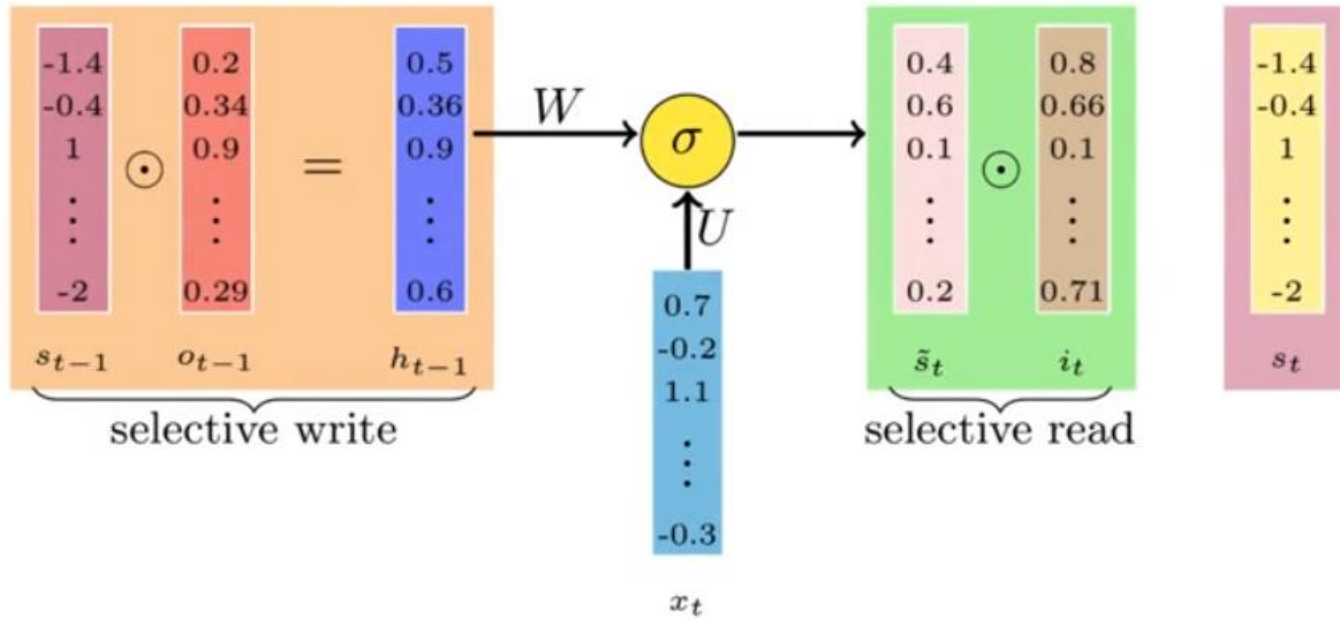


$$\tilde{s}_t = \sigma(Ux_t + Wh_{t-1} + b)$$

✓ \tilde{s}_t thus captures all the information from the previous state h_{t-1} and the current input x_t

✓ However, we may not want to use all this new information and only selectively read from it before constructing the new cell state

Selective Read

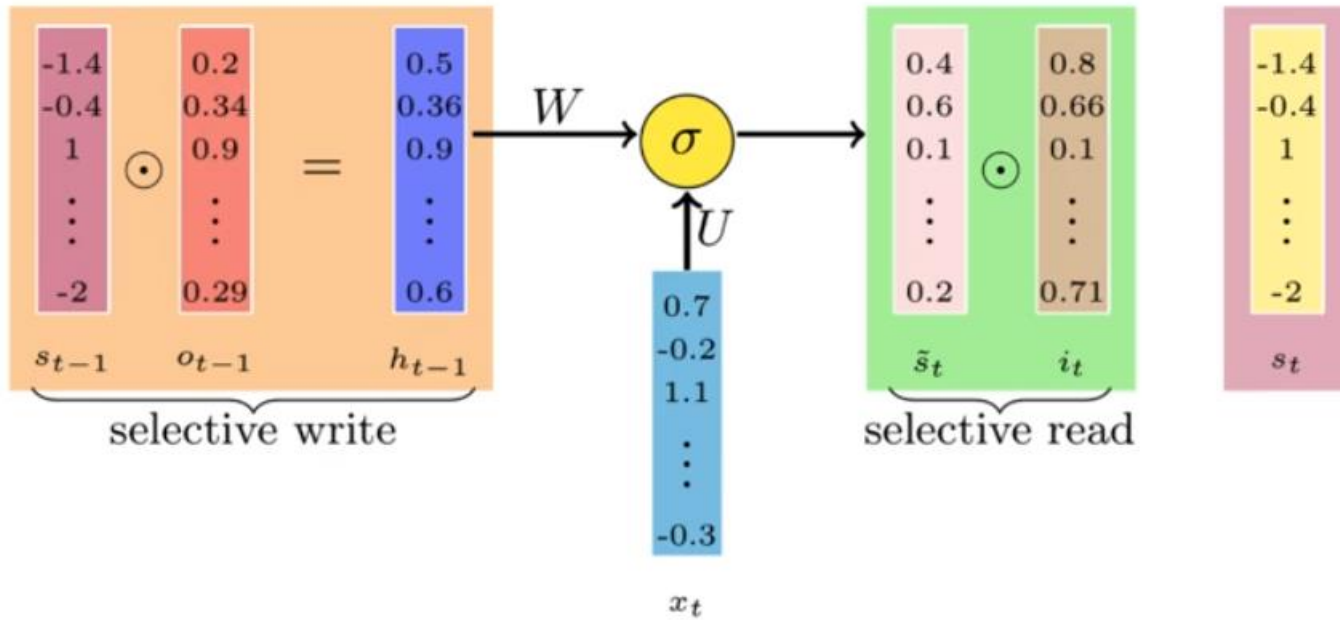


$$i_t = \sigma(U_i x_t + W_i h_{t-1} + b_i)$$

$$= \tilde{s}_t \odot i_t$$

i_t is called the **input** gate

Selective Read



Previous state:

s_{t-1}

Output gate:

$$o_{t-1} = \sigma(W_o h_{t-2} + U_o x_{t-1} + b_o)$$

Selectively Write:

$$h_{t-1} = o_{t-1} \odot \sigma(s_{t-1})$$

Current (temporary) state:

$$\tilde{s}_t = \sigma(W h_{t-1} + U x_t + b)$$

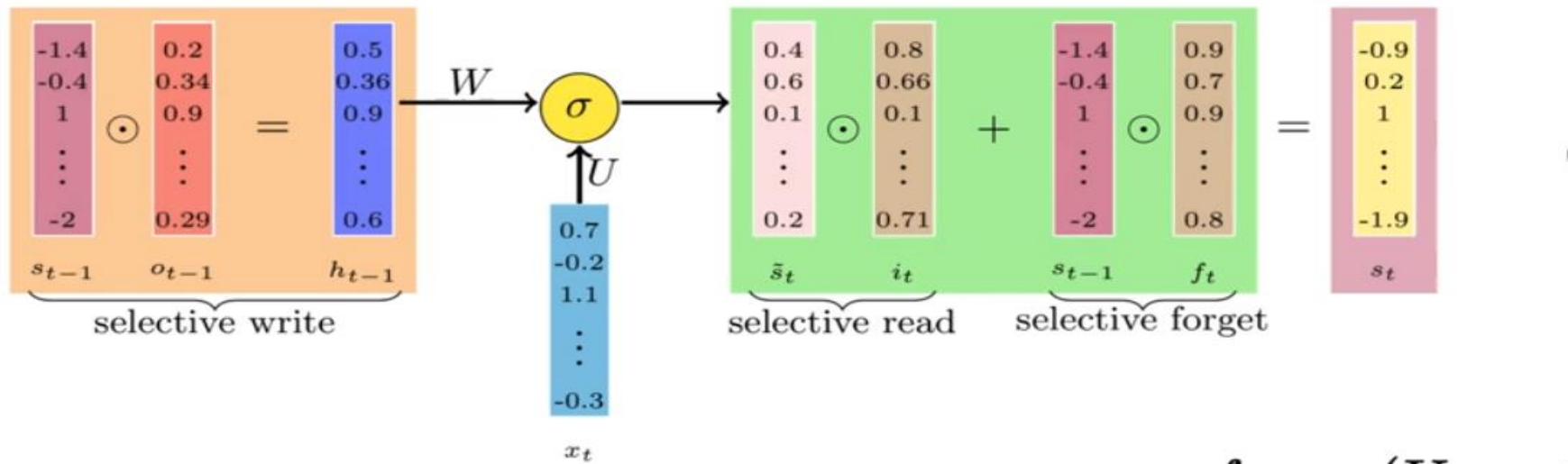
Input gate:

$$i_t = \sigma(W_i h_{t-1} + U_i x_t + b_i)$$

Selectively Read:

$$i_t \odot \tilde{s}_t$$

Summary – till selective read and write

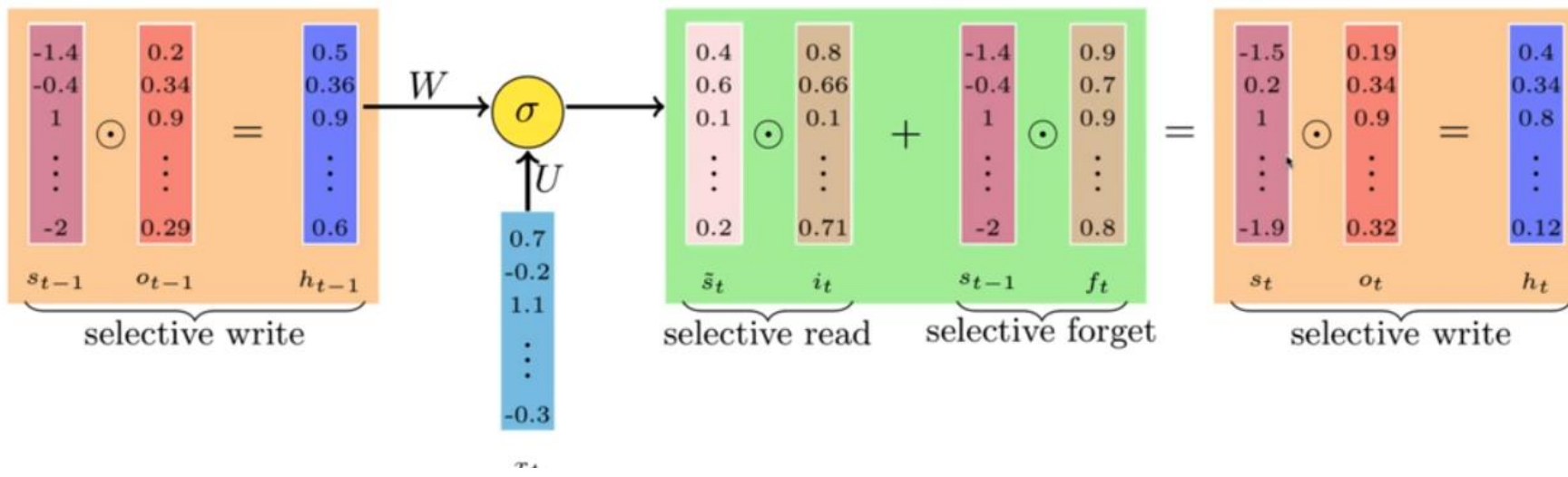


How do we combine \tilde{s}_t and s_{t-1} to get the new state s_t

$$f_t = \sigma(U_f x_t + W_f h_{t-1} + b_f)$$

$$s_t = \tilde{s}_t \odot i_t + s_{t-1} \odot f_t$$

Selective Forget



Gates:

$$o_t = \sigma(W_o h_{t-1} + U_o x_t + b_o)$$

$$i_t = \sigma(W_i h_{t-1} + U_i x_t + b_i)$$

$$f_t = \sigma(W_f h_{t-1} + U_f x_t + b_f)$$

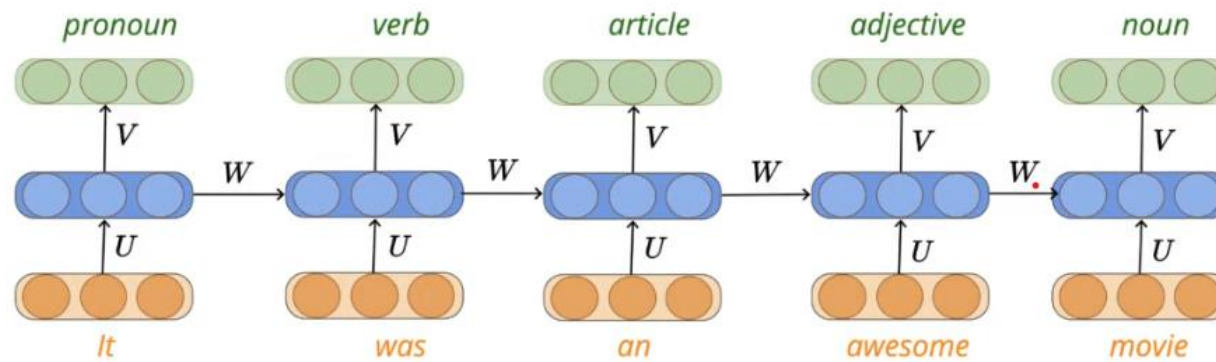
States:

$$\tilde{s}_t = \sigma(W h_{t-1} + U x_t + b)$$

$$s_t = f_t \odot s_{t-1} + i_t \odot \tilde{s}_t$$

$$h_t = o_t \odot \sigma(s_t)$$

Full set of equations
(Selective Read, Selective Write and Selective Forget)



Gates:

$$o_t = \sigma(W_o h_{t-1} + U_o x_t + b_o)$$

$$i_t = \sigma(W_i h_{t-1} + U_i x_t + b_i)$$

$$f_t = \sigma(W_f h_{t-1} + U_f x_t + b_f)$$

States:

$$\tilde{s}_t = \sigma(W h_{t-1} + U x_t + b)$$

$$s_t = f_t \odot s_{t-1} + i_t \odot \tilde{s}_t$$

$$h_t = o_t \odot \sigma(s_t)$$

Long Short Term Memory Cells

- ✓ LSTM has many variants which include different number of gates and also different arrangement of gates
- ✓ The one which we just saw is one of the most popular variants of LSTM
- ✓ Another equally popular variant of LSTM is Gated Recurrent Unit which we will see next

Gates:

$$o_t = \sigma(W_o h_{t-1} + U_o x_t + b_o)$$

$$i_t = \sigma(W_i h_{t-1} + U_i x_t + b_i)$$

$$f_t = \sigma(W_f h_{t-1} + U_f x_t + b_f)$$

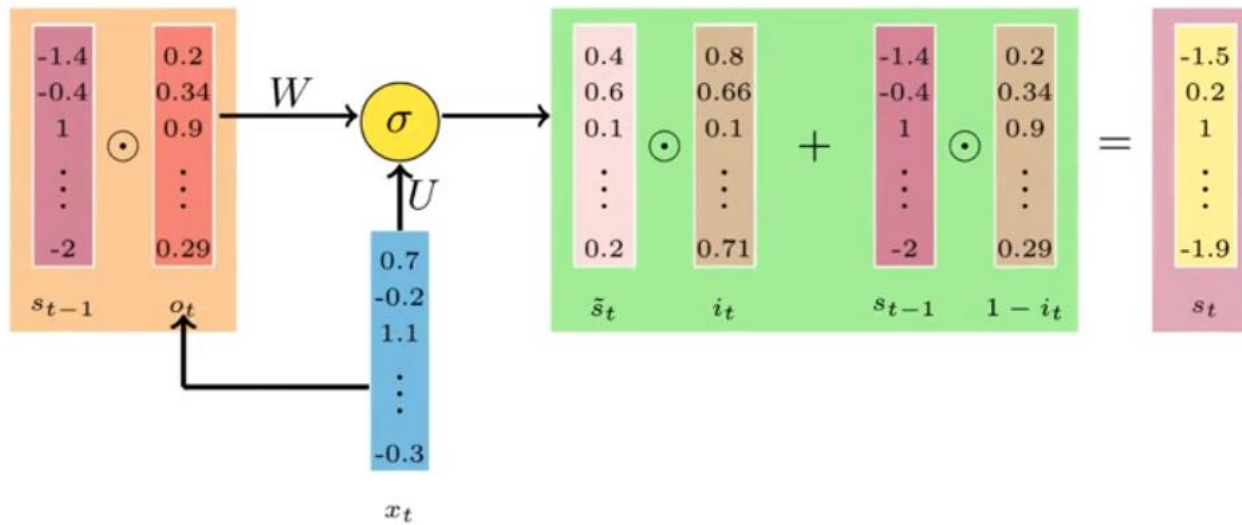
States:

$$\tilde{s}_t = \sigma(W h_{t-1} + U x_t + b)$$

$$s_t = f_t \odot s_{t-1} + i_t \odot \tilde{s}_t$$

$$h_t = o_t \odot \sigma(s_t)$$

Long Short Term Memory Cells



Gates:

$$o_t = \sigma(W_o s_{t-1} + U_o x_t + b_o)$$

$$i_t = \sigma(W_i s_{t-1} + U_i x_t + b_i)$$

States:

$$\tilde{s}_t = \sigma(W(o_t \odot s_{t-1}) + U x_t + b)$$

$$s_t = (1 - i_t) \odot s_{t-1} + i_t \odot \tilde{s}_t$$

Gated Recurrent Units (Fewer Gates)